NSN 5961-01-191-9450

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-191-9450 **Inclosure Material:** Plastic **Component Name And Quantity:** 4 transistor **Mounting Method:** Press fit **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source all transistor **Current Rating Per Characteristic:** 225.00 milliamperes drain current all transistor **Power Rating Per Characteristic:** 800.0 milliwatts total power dissipation all transistor **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 14 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli

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